

the **abdus salam** international centre for theoretical physics 40 anniversary 2004

SMR.1587 - 9

SCHOOL AND WORKSHOP ON QUANTUM ENTANGLEMENT, DECOHERENCE, INFORMATION, AND GEOMETRICAL PHASES IN COMPLEX SYSTEMS (1 November - 12 November 2004)

Propagation, collision and entanglement of electron wavepackets in quantum dot arrays

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These are preliminary lecture notes, intended only for distribution to participants



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Outline



- Design and Multidot Experiments
- Mathematical Formalism
 - Mott-Hubbard Hamiltonian
 - Parameters and Approximations
 - Quantum Monte-Carlo Stochastic Wavefunctions
- One Excess (mobile) Electron
- Two Excess Electrons, Bonding and Collisions
- Quantum Entanglement with Heisenberg Exchange Interaction
- Quantum Channel with QD Array
- Summary

Design of Quantum Dot Array



Schematic drawing of the Heterostructure



- ~ 5 nm thick AlGaAs layer is sandwiched between two GaAs layers
 2DEG is formed at the top GaAs-AlGaAs interface
- Array of metallic gates on top of the structure (with externally controlled voltages) restricts the movement of electrons and forms a chain of 0D QDs.
- Resonant tunneling of electrons between the QDs mediates their coherent propagation in 1D

Multidot Experiments: Static Properties



SEM photograph and schematic view of a chain of 3 QDs





Conductance vs. gate voltage V₅ for double–dot system (QDs 2 and 3)

$$t_{23} = 0.03$$
 (a)
= 0.88 (b)
= 1.37 (c)
= 1.94 (d) X $e^{2/h}$

F. Waugh et al., PRL 75, 705 (1995)

Multidot Experiments: Static Properties



Conductance vs. gate voltage V_{q2} for a chain of 15 QDs



L. Kouwenhoven et al., PRL 65, 361 (1990)



$$H = \sum_{j,\alpha} \varepsilon_{j\alpha} a_{j\alpha}^{\dagger} a_{j\alpha} + \frac{1}{2} \sum_{j} U n_j (n_j - 1) + \sum_{j=i\pm 1,\alpha} t_{ij,\alpha} a_{i\alpha}^{\dagger} a_{j\alpha} + \sum_{i< j} V_{ij} n_i n_j$$

• $a_{j\alpha}^{\dagger}(a_{j\alpha})$ creation (annihilation) operator for electron in state $|\alpha\rangle$ with energy $\varepsilon_{j\alpha}$ and electronic orbital $\psi_j(\mathbf{r})$

•
$$n_j = \sum_{\alpha} a_{j\alpha}^{\dagger} a_{j\alpha}$$
 electron number operator
• $U = \frac{e^2}{8\pi\epsilon_r\epsilon_0} \int d\mathbf{r} d\mathbf{r}' \frac{|\psi_j(\mathbf{r})|^2 |\psi_j(\mathbf{r}')|^2}{|\mathbf{r}-\mathbf{r}'|} \simeq \frac{e^2}{C_g}$ On-site Coulomb repulsion
 $C_g \simeq 8\epsilon_r\epsilon_0 R$ self-capacitance for 2D disk-shaped QD ($\epsilon_r \simeq 13$ for GaAs)

• $t_{ij} = \frac{\hbar^2}{2m^*} \int d\mathbf{r} \, \psi_i^*(\mathbf{r}) \nabla^2 \psi_j(\mathbf{r})$ Interdot tunneling rate m^* electron effective mass ($m^* \simeq 0.067m_e$ in GaAs)

• $V_{ij} \simeq U\left(\frac{C}{C_g}\right)^{|i-j|}$ Interdot Coulomb repulsion partially screened by image charges (interdot capacitance $C \ll C_g$)



Assumptions

- Near-neighbor tunnel t_{ij} and electrostatic $V_{ij} = V$ interactions $\Rightarrow t_{ij}, V_{ij} \neq 0$, for $i = j \pm 1$
- Single-particle level spacing $\Delta \varepsilon > t_{ij}$ ($\Delta \varepsilon \simeq \frac{\hbar^2 \pi}{m^* R^2}$ in 2D potential) ⇒ one double- (spin-) degenerate level per QD ($\alpha \in \{\uparrow, \downarrow\}$)
- Coulomb Blockade regime $U \gg \Delta \varepsilon > t_{ij}$ ⇒ at most one electron per QD

Typical experimental parameters

for $30-50~\mathrm{nm}$ size GaAs/AlGaAs QDs, separated by $\sim 100~\mathrm{nm}$

- Tunneling rates $t_{ij} \sim 0.05 \text{ meV}$
- Single-particle level spacing $\Delta \varepsilon \sim 1.0 \text{ meV}$
- On-site Coulomb repulsion $U \sim 15 \text{ meV}$
- Thermal energy at $T \sim 2 10$ mK is $k_{\rm B}T \sim 0.2 1 \ \mu {\rm eV}$

1D Array of N Quantum Dots





• The array is initially doped with n = 1, 2... ($n \ll N$) electrons

- Lower tunnel barriers and raise the confining potentials
 deplete the array
- Lower confining potentials and open and close the tunnel barriers
 dope preselected QDs with single electrons
- Nth QD is dissipatively coupled to a SED with $\gamma \ll t_{ij}$
 - \Rightarrow detector monitors the evolution

Quantum Monte Carlo Simulations



- Disorder due to
 - Structure imperfections & Gate voltage fluctuations
 - Electron-phonon interactions & Thermal fluctuations
 - $\Rightarrow \varepsilon_{ij}, t_{ij}$ —Gaussian random numbers with mean ε_0, t_0 & FWHM $\delta \varepsilon = 0.1 t_0 (\sim 5 \,\mu \text{eV}), \, \delta t = 0.05 t_0 (\sim 2.5 \,\mu \text{eV})$
- Detector signal with $\gamma = 0.2t_0 (\sim 2.4 \text{ GHz})$
 - Generate random $r (0 \le r < 1)$
 - Propagate $|\Psi(\tau)\rangle$ with $H_{\text{eff}} = H \frac{i}{2}\gamma n_N$ until $||\Psi(\tau)||^2 = r$ \Rightarrow Quantum Jump $|\Psi\rangle \rightarrow \sum_{\alpha} \frac{a_{N\alpha} |\Psi\rangle}{\sqrt{\langle\Psi| a_{N\alpha}^{\dagger} a_{N\alpha} |\Psi\rangle}}$

• Continue (with new r) until $|\Psi(au)
angle=0$

One Mobile Electron





(a) Equal Tunneling Rates $t_{jj+1} = t_0 (\pm \delta t)$ (Equal Coupling – EC) \Rightarrow Incommensurate eigenenergies $\lambda_k = 2t_0 \cos\left(\frac{k\pi}{N+1}\right)$ Amplitudes $A_j^{\alpha} = \frac{2}{N+2} \sum_{k=1}^{N} \exp\left[-i2t_0 \tau \cos\left(\frac{k\pi}{N+1}\right)\right] \sin\left(\frac{jk\pi}{N+1}\right) \sin\left(\frac{k\pi}{N+1}\right)$

WP spreading and delocalization – dispersion

One Mobile Electron





(b) Tunneling Rates $t_{jj+1} = t_0 \sqrt{(N-j)j}$ ($\pm \delta t$) (Optimal or SM Coupling – OC) \Rightarrow Commensurate eigenenergies $\lambda_k = t_0(2k - N - 1)$ Amplitudes $A_j^{\alpha} = \left(\begin{array}{c} N-1\\ j-1 \end{array}\right)^{1/2} [-i\sin(t_0\tau)]^{(j-1)}\cos(t_0\tau)^{(N-j)}$ $|A_1^{\alpha}|^2 = \cos(t_0\tau)^{2(N-1)} |A_N^{\alpha}|^2 = \sin(t_0\tau)^{2(N-1)}$: Revivals at $t_0\tau = \frac{m\pi}{2}$

Perfectly periodic behavior

Two Mobile Electrons





(a) EC $t_{jj+1} = t_0 \& V = 0$ (No Repulsion)

WP dispersion as in 1e case

Two Mobile Electrons





(b) OC $t_{jj+1} = t_0 \sqrt{(N-j)j}$ & V = 0 (No Repulsion) \Rightarrow Commensurate (2N - 3 distinct) eigenenergies $\lambda_k = t_0(2k - N + 2)$ Amplitudes for states $|i_{\alpha}, j_{\beta}\rangle$ $B_{ij}^{\alpha\beta} = \left[\frac{(j-i)^2(N-1)!(N-2)!}{(i-1)!(j-1)!(N-i)!(N-j)!}\right]^{1/2} [-i\sin(t_0\tau)]^{i+j-3}\cos(t_0\tau)^{2N-i-j-1}$ $|B_{12}^{\alpha\beta}|^2 = \cos(t_0\tau)^{4N-8} |B_{N-1N}^{\alpha\beta}|^2 = \sin(t_0\tau)^{4N-8}$: Revivals at $t_0\tau = \frac{m\pi}{2}$

Perfectly periodic behavior

Two Mobile Electrons: Bonding





(c) EC $t_{jj+1} = t_0 \& 0 < V \le t_0$ (Weak Repulsion)

Enhanced dispersion of WP due to inhomogeneity

Two Mobile Electrons: Bonding





(d) EC $t_{jj+1} = t_0 \& V > t_0$ (Strong Repulsion)

Energy of $|j, j \pm 1\rangle$ is larger

than of $|j, j \pm 2\rangle$ etc., by $V > t_0$



 \Rightarrow transitions $|j, j \pm 1 \rangle \rightarrow |j, j \pm 2 \rangle$ are non-resonant

Effective tunneling rate for $|j, j+1\rangle \rightarrow |j+1, j+2\rangle$ is $t_{\text{eff}}^{(2)} = \frac{t_0^2}{V} < t_0$ \Rightarrow slow propagation

Two-electron bonding via Coulomb repulsion $(V > 0 \Rightarrow 2e \text{ bound state is unstable})$

Two Mobile Electrons: Collisions





(a),(c),(d) Equal Coupling $t_{jj+1} = t_0$: Electrons collide in the center \Rightarrow Each electron has $\frac{N}{2}$ accessible QDs

WP dispersion as in 1e case

Two Mobile Electrons: Collisions





(b) Optimal Coupling $t_{jj+1} = t_0 \sqrt{(N-j)j}$: Collisions & revivals at $t_0 \tau = \frac{m\pi}{4} \leftarrow$ Each electron has $\frac{N}{2}$ accessible QDs Perfectly periodic behavior

Two Mobile Electrons: Monte-Carlo Smls.





Decoherence & Decay

$$\Gamma_{\text{coherence}} \simeq \delta \varepsilon + \delta t, \quad \Gamma_{\text{population}} \simeq \gamma / N$$



 $t_e \ll U$ – Adiabatic elimination of nonresonant (virtual) $|L_{\uparrow}L_{\downarrow}\rangle$, $|R_{\uparrow}R_{\downarrow}\rangle$ \Rightarrow effective Heisenberg exchange interaction $|L_{\uparrow}R_{\downarrow}\rangle \leftrightarrow |L_{\downarrow}R_{\uparrow}\rangle$

$$H_s(\tau) = J(\tau)\vec{S}_L \cdot \vec{S}_R, \quad J(\tau) = -\frac{4t_e^2(\tau)}{U}$$

• For
$$\theta \equiv \int J(\tau) d\tau = \pi$$

 \Rightarrow swap $|L_{\alpha}R_{\beta}\rangle \rightarrow i |L_{\beta}R_{\alpha}\rangle$ ($\alpha, \beta \in \{\uparrow, \downarrow\}$)



 $t_e \ll U$ – Adiabatic elimination of nonresonant (virtual) $|L_{\uparrow}L_{\downarrow}\rangle$, $|R_{\uparrow}R_{\downarrow}\rangle$ \Rightarrow effective Heisenberg exchange interaction $|L_{\uparrow}R_{\downarrow}\rangle \leftrightarrow |L_{\downarrow}R_{\uparrow}\rangle$

$$H_s(\tau) = J(\tau)\vec{S}_L \cdot \vec{S}_R, \quad J(\tau) = -\frac{4t_e^2(\tau)}{U}$$

• For
$$\theta \equiv \int J(\tau) d\tau = \pi/2$$

 $\Rightarrow \sqrt{\text{SWAP}} |\phi\rangle = |L_{\uparrow}R_{\downarrow}\rangle \rightarrow \frac{1}{\sqrt{2}}(|L_{\uparrow}R_{\downarrow}\rangle + i |L_{\downarrow}R_{\uparrow}\rangle)$
For $\theta = \pi/2$ with $t_e(\tau) = t_e^{\max} \operatorname{sech}[(\tau - \tau^{\max})/\Delta\tau] \Rightarrow (t_e^{\max})^2 \Delta\tau = \pi U/16$

Loss, DiVincenzo (1998)

Quantum Channel with QD Array





(i) Coherent transport via OC & trapping $|1_{\uparrow}N_{\downarrow}\rangle \rightarrow |L_{\uparrow}R_{\downarrow}\rangle$ (ii) $\sqrt{\text{swap}}$ via Exchange interaction $|L_{\uparrow}R_{\downarrow}\rangle \rightarrow \frac{1}{\sqrt{2}}(|L_{\uparrow}R_{\downarrow}\rangle + i |L_{\downarrow}R_{\uparrow}\rangle)$ (iii) Reverse of (i) $\frac{1}{\sqrt{2}}(|L_{\uparrow}R_{\downarrow}\rangle + i |L_{\downarrow}R_{\uparrow}\rangle) \rightarrow \frac{1}{\sqrt{2}}(|1_{\uparrow}N_{\downarrow}\rangle + i |1_{\downarrow}N_{\uparrow}\rangle)$

• Monte Carlo simulations \Rightarrow Fidelity F = 0.98 N = 20, L = N/2 with $U = 100t_0, t_e^{\max} = 6t_0$, Disorder prms. $\delta \varepsilon = 0.1t_0, \delta t = 0.05t_0$

Summary & Conclusions



- By manipulating the absolute values and relative magnitudes of tunneling rates between QDs in a 1D array, it is possible to
 - accelerate/decelerate electron wavepacket propagation dynamics
 - enhance/suppress wavepacket spreading and interference
- By manipulating the interdot Coulomb repulsion, it is possible to
 - form bonded multi-electron states
 - control electron collisions
- Possible applications for Quantum Computation and Information
 - Entanglement of 2 qubits (represented by spin states of QD electrons) via controlled spin-exchange collisions
 - Quantum Communication & Information Transport via Quantum
 Channel
 Quantum Computer with QDs



Analogies with Other Systems



- Spin-wave propagation in spin chains
- EM wave propagation in periodic structures (PBG materials & Waveguide lattices)
- Matter-wave (BEC) propagation in optical lattices